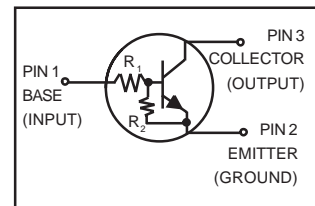
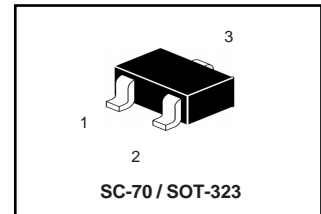


## Bias Resistor Transistor

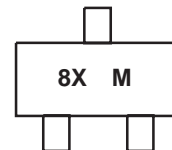
### NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SC-70/SOT-323 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Available in 8 mm embossed tape and reel  
Use the Device Number to order the 7 inch/3000 unit reel.
- Pb-Free package is available



#### MARKING DIAGRAM



8x = Specific Device Code  
x = (See Marking Table)  
M = Date Code

#### DEVICE MARKING INFORMATION

See specific marking information in the device marking table on page 2 of this data sheet.

#### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	Vdc
Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current	$I_C$	100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	202 (Note 1.) 310 (Note 2.) 1.6 (Note 1.) 2.5 (Note 2.)	mW mW/ $^\circ\text{C}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	618 (Note 1.) 403 (Note 2.)	$^\circ\text{C}/\text{W}$
Thermal Resistance – Junction-to-Lead	$R_{\theta JL}$	280 (Note 1.) 332 (Note 2.)	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0 x 1.0 inch Pad

## DEVICE MARKING RESISTOR VALUES AND ORDERING INFORMATION

Device	Package	Marking	R1(K)	R2(K)	Shipping
LMUN5211T1G	SC-70/SOT-323	8A	10	10	3000/Tape&Reel
LMUN5211T3G	SC-70/SOT-323	8A	10	10	10000/Tape&Reel
LMUN5212T1G	SC-70/SOT-323	8B	22	22	3000/Tape&Reel
LMUN5212T3G	SC-70/SOT-323	8B	22	22	10000/Tape&Reel
LMUN5213T1G	SC-70/SOT-323	8C	47	47	3000/Tape&Reel
LMUN5213T3G	SC-70/SOT-323	8C	47	47	10000/Tape&Reel
LMUN5214T1G	SC-70/SOT-323	8D	10	47	3000/Tape&Reel
LMUN5214T3G	SC-70/SOT-323	8D	10	47	10000/Tape&Reel
LMUN5215T1G(Note 3)	SC-70/SOT-323	8E	10	∞	3000/Tape&Reel
LMUN5215T3G	SC-70/SOT-323	8E	10	∞	10000/Tape&Reel
LMUN5216T1G(Note 3)	SC-70/SOT-323	8F	4.7	∞	3000/Tape&Reel
LMUN5216T3G	SC-70/SOT-323	8F	4.7	∞	10000/Tape&Reel
LMUN5230T1G(Note 3)	SC-70/SOT-323	8G	1	1	3000/Tape&Reel
LMUN5230T3G	SC-70/SOT-323	8G	1	1	10000/Tape&Reel
LMUN5231T1G(Note 3)	SC-70/SOT-323	8H	2.2	2.2	3000/Tape&Reel
LMUN5231T3G	SC-70/SOT-323	8H	2.2	2.2	10000/Tape&Reel
LMUN5232T1G(Note 3)	SC-70/SOT-323	8J	4.7	4.7	3000/Tape&Reel
LMUN5232T3G	SC-70/SOT-323	8J	4.7	4.7	10000/Tape&Reel
LMUN5233T1G(Note 3)	SC-70/SOT-323	8K	4.7	47	3000/Tape&Reel
LMUN5233T3G	SC-70/SOT-323	8K	4.7	47	10000/Tape&Reel
LMUN5234T1G(Note 3)	SC-70/SOT-323	8L	22	47	3000/Tape&Reel
LMUN5234T3G	SC-70/SOT-323	8L	22	47	10000/Tape&Reel
LMUN5235T1G(Note 3)	SC-70/SOT-323	8M	2.2	47	3000/Tape&Reel
LMUN5235T3G	SC-70/SOT-323	8M	2.2	47	10000/Tape&Reel
LMUN5236T1G(Note 3)	SC-70/SOT-323	8N	100	100	3000/Tape&Reel
LMUN5236T3G	SC-70/SOT-323	8N	100	100	10000/Tape&Reel
LMUN5237T1G(Note 3)	SC-70/SOT-323	8P	47	22	3000/Tape&Reel
LMUN5237T3G	SC-70/SOT-323	8P	47	22	10000/Tape&Reel

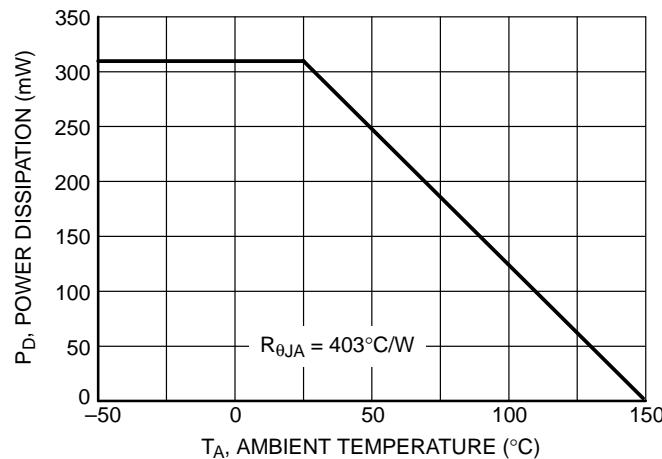
3. New devices. Updated curves to follow in subsequent data sheets.



**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>ON CHARACTERISTICS</b> (Note 5.) (Continued)					
Output Voltage (off) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.050\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.25\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )	$V_{OH}$	4.9	–	–	Vdc
	LMUN5230T1G				
	LMUN5215T1G				
	LMUN5216T1G				
	LMUN5233T1G				
Input Resistor	$R_1$	7.0	10	13	$\text{k}\Omega$
	LMUN5211T1G	15.4	22	28.6	
	LMUN5212T1G	32.9	47	61.1	
	LMUN5213T1G	7.0	10	13	
	LMUN5214T1G	7.0	10	13	
	LMUN5215T1G	3.3	4.7	6.1	
	LMUN5216T1G	0.7	1.0	1.3	
	LMUN5230T1G	1.5	2.2	2.9	
	LMUN5231T1G	3.3	4.7	6.1	
	LMUN5232T1G	3.3	4.7	6.1	
	LMUN5233T1G	15.4	22	28.6	
	LMUN5234T1G	1.54	2.2	2.86	
	LMUN5235T1G	70	100	130	
	LMUN5236T1G	32.9	47	61.1	
	LMUN5237T1G				
Resistor Rati	$R_1/R_2$	0.8	1.0	1.2	
LMUN5211T1G/LMUN5212T1G/LMUN5213T1G/ LMUN5236T1G		0.17	0.21	0.25	
LMUN5214T1G		–	–	–	
LMUN5215T1G/LMUN5216T1G		0.8	1.0	1.2	
LMUN5230T1G/LMUN5231T1G/LMUN5232T1G		0.055	0.1	0.185	
LMUN5233T1G		0.38	0.47	0.56	
LMUN5234T1G		0.038	0.047	0.056	
LMUN5235T1G		1.7	2.1	2.6	
LMUN5237T1G					

5. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%



**Figure 1. Derating Curve**

## TYPICAL ELECTRICAL CHARACTERISTICS – LMUN5211T1G

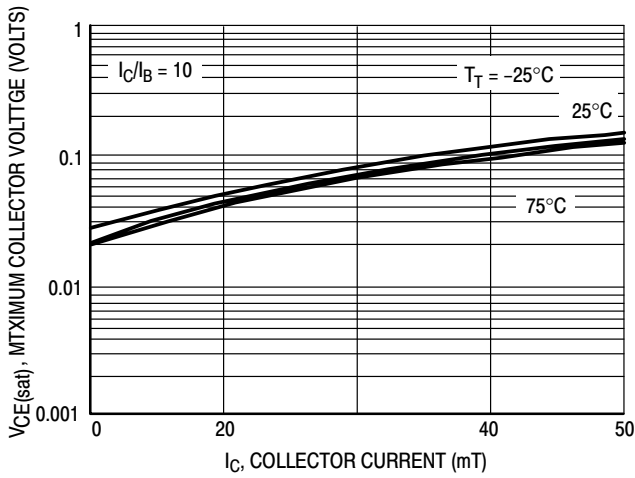


Figure 2.  $V_{CE(sat)}$  versus  $I_C$

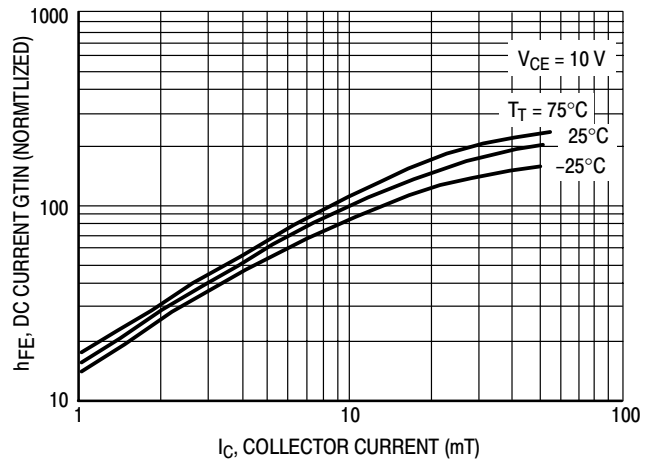


Figure 3. DC Current Gain

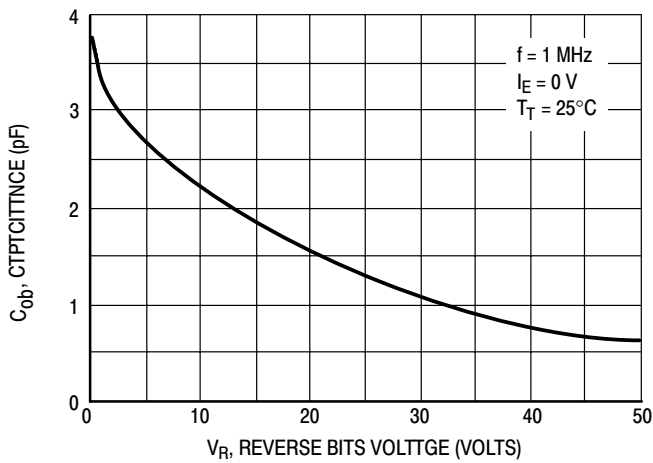


Figure 4. Output Capacitance

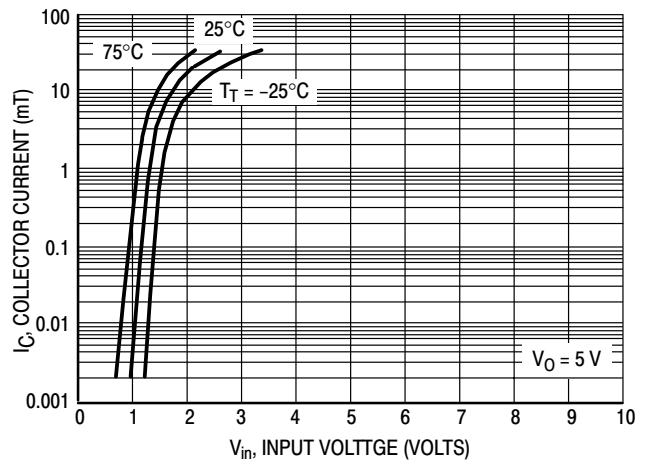


Figure 5. Output Current versus Input Voltage

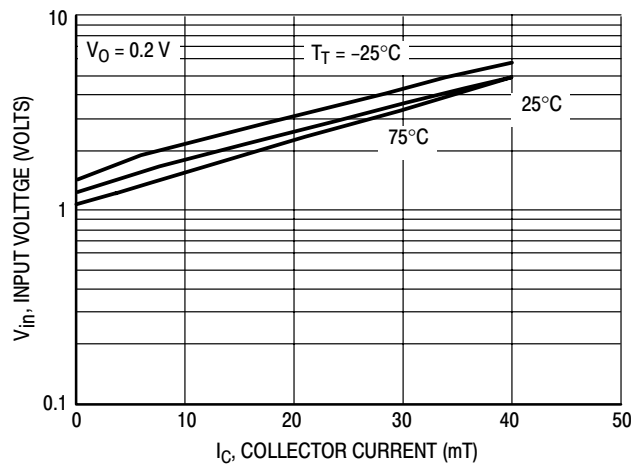


Figure 6. Input Voltage versus Output Current

## TYPICAL ELECTRICAL CHARACTERISTICS – LMUN5212T1G

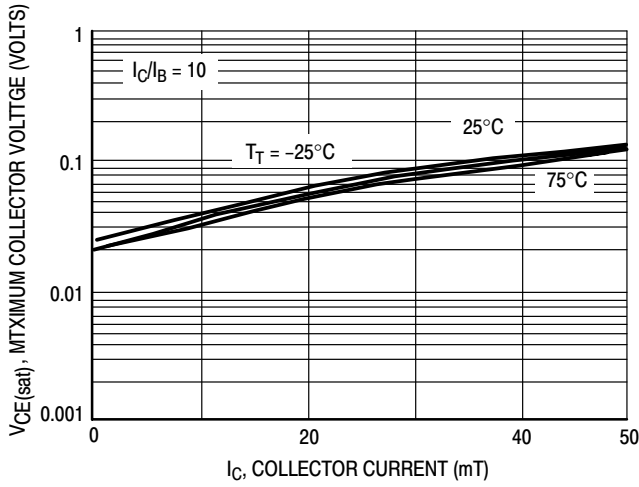


Figure 7.  $V_{CE(sat)}$  versus  $I_C$

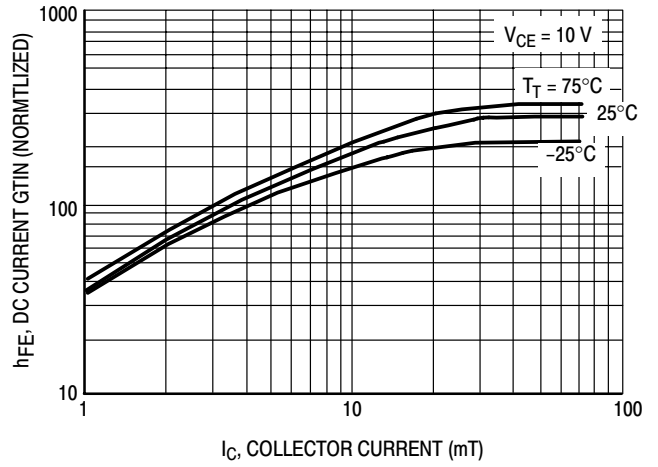


Figure 8. DC Current Gain

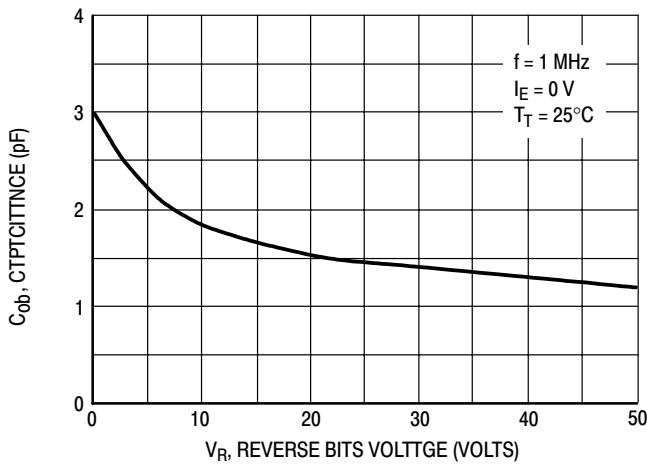


Figure 9. Output Capacitance

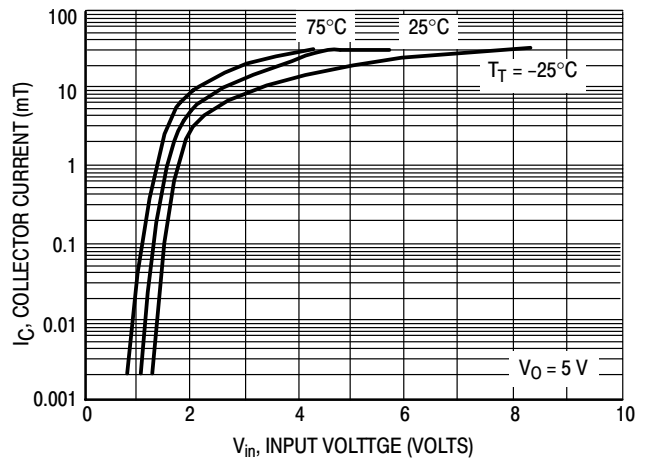


Figure 10. Output Current versus Input Voltage

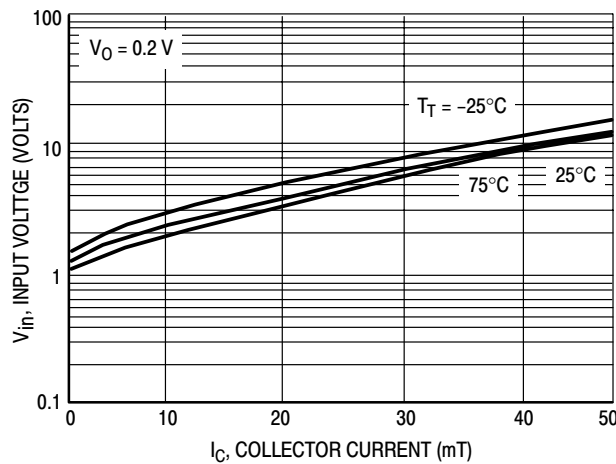


Figure 11. Input Voltage versus Output Current

## TYPICAL ELECTRICAL CHARACTERISTICS – LMUN5213T1G

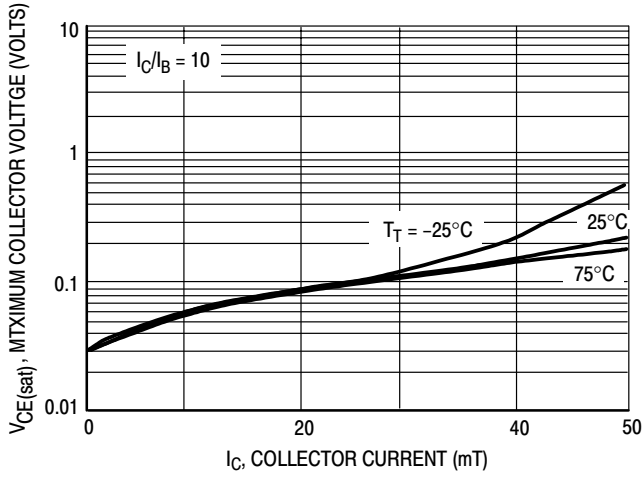


Figure 12.  $V_{CE(sat)}$  versus  $I_C$

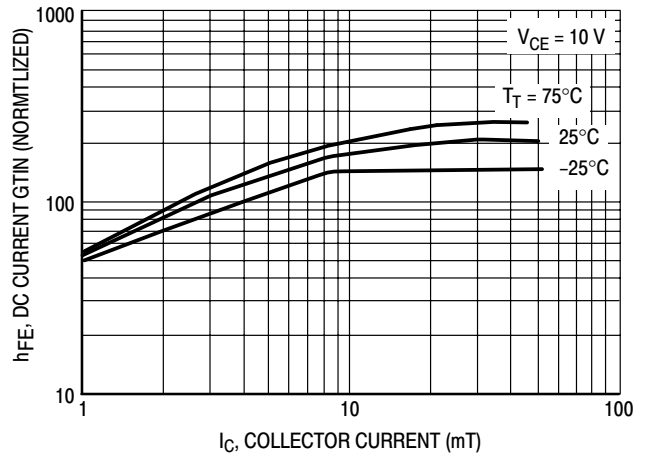


Figure 13. DC Current Gain

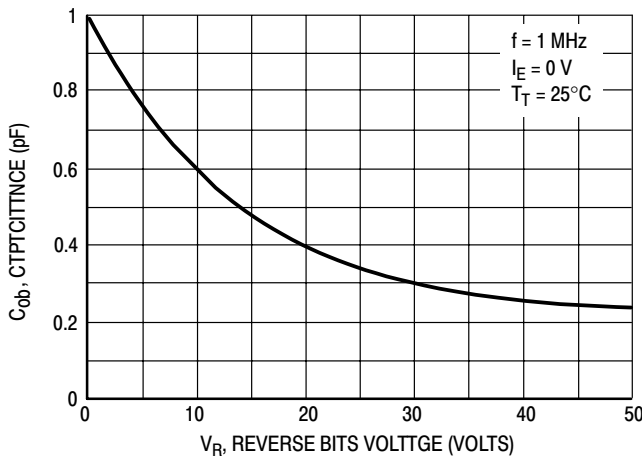


Figure 14. Output Capacitance

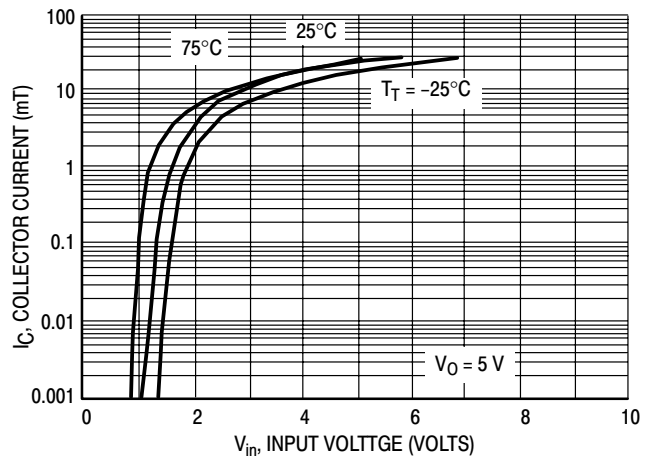


Figure 15. Output Current versus Input Voltage

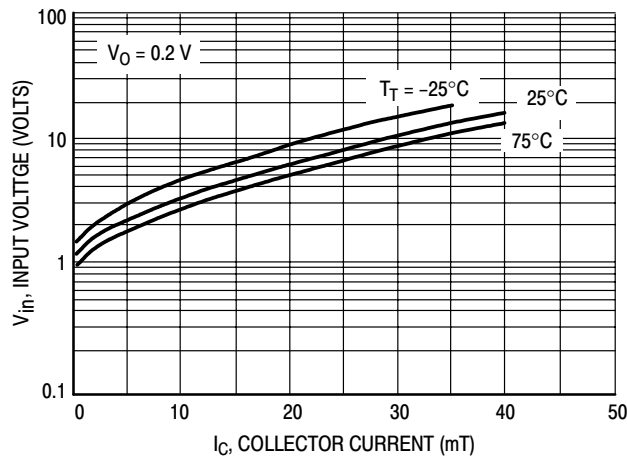


Figure 16. Input Voltage versus Output Current

## TYPICAL ELECTRICAL CHARACTERISTICS – LMUN5214T1G

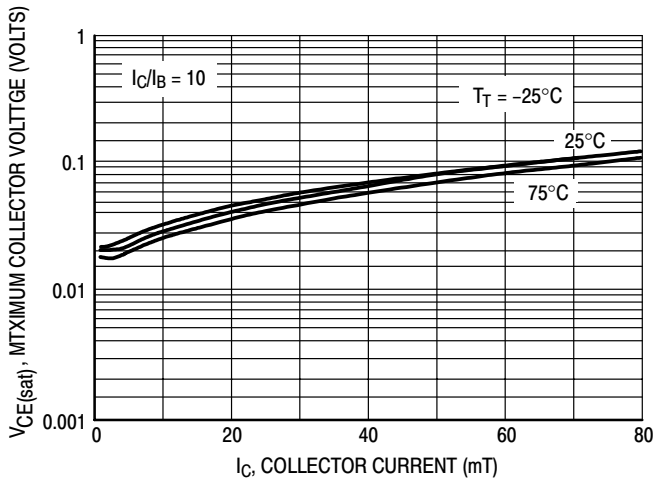


Figure 17.  $V_{CE(sat)}$  versus  $I_C$

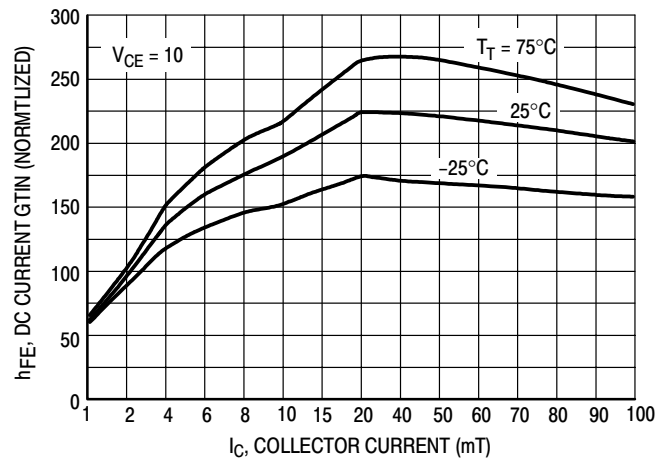


Figure 18. DC Current Gain

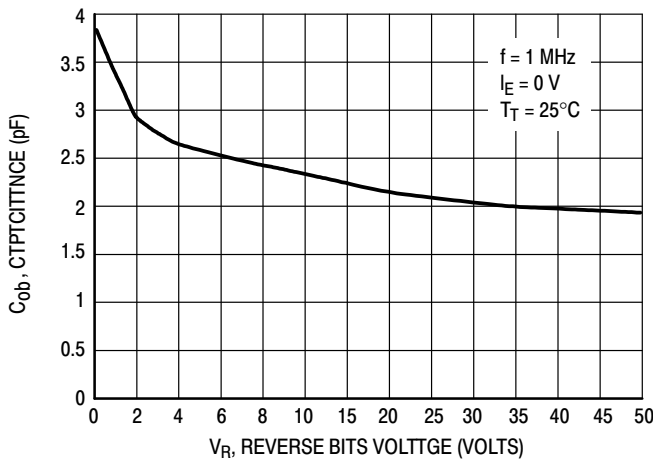


Figure 19. Output Capacitance

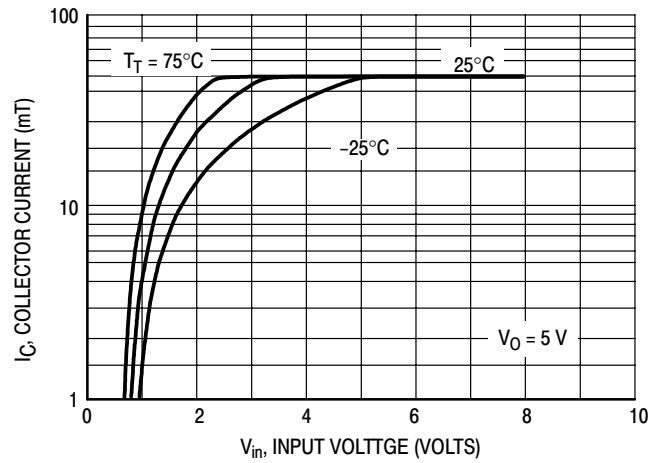


Figure 20. Output Current versus Input Voltage

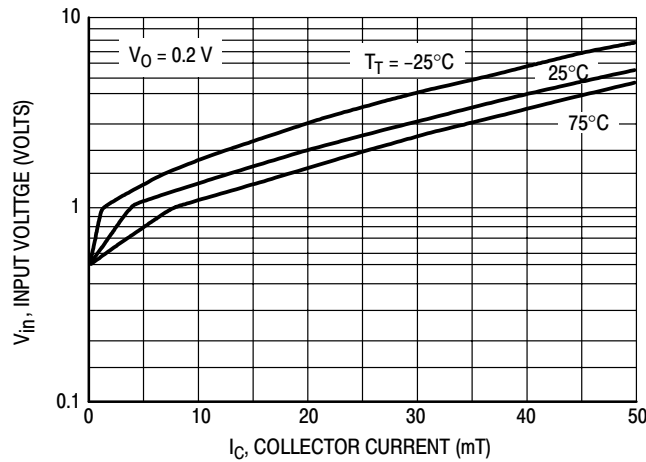


Figure 21. Input Voltage versus Output Current

## TYPICAL APPLICATIONS FOR NPN BRTs

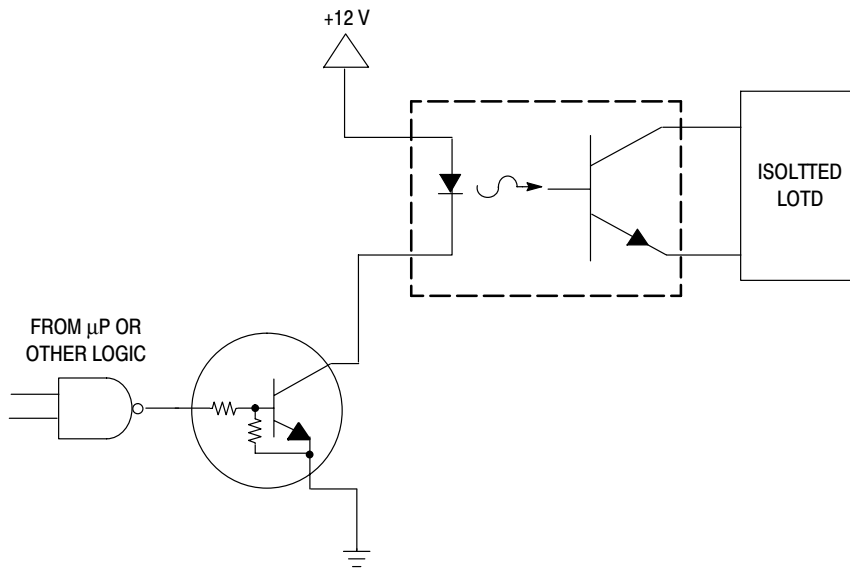


Figure 22. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

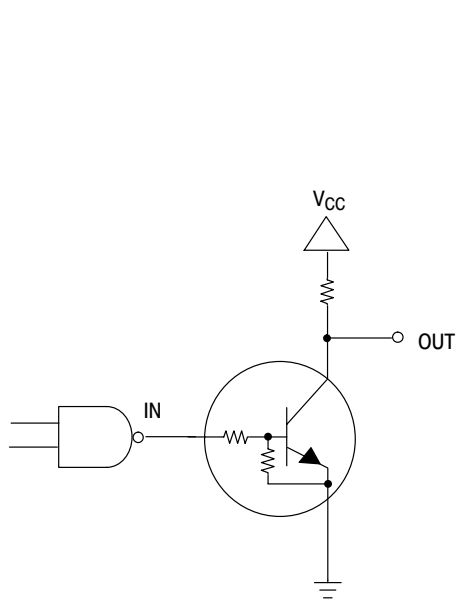


Figure 23. Open Collector Inverter:  
Inverts the Input Signal

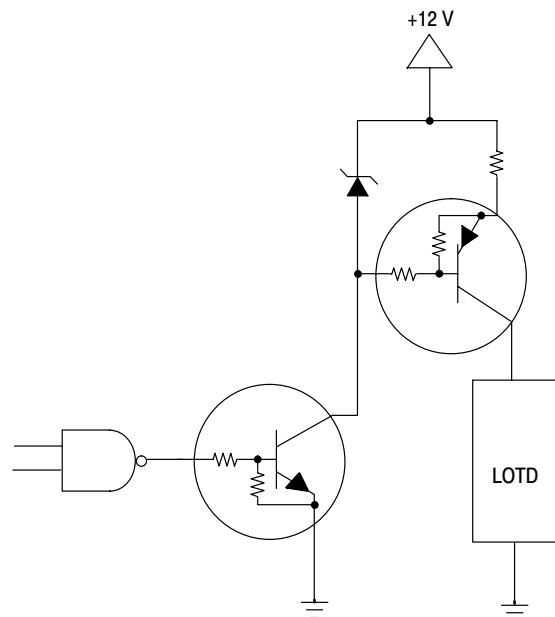


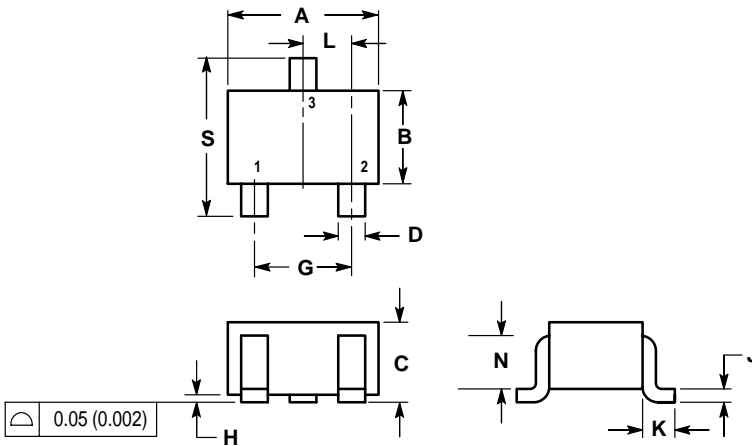
Figure 24. Inexpensive, Unregulated Current Source

## SC-70 / SOT-323

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
S	0.079	0.095	2.00	2.40



- PIN 1. BASE  
 PIN 2. EMITTER  
 PIN 3. COLLECTOR

